# An Improved Procedure for Estimating the Metal Surface Area of Supported Copper Catalysts

Supported Cu catalysts are of immense industrial importance, but a rapid and reliable method for estimating the exposed Cu metal surface, and hence the number of Cu atoms available to act catalytically, has not yet been described.

Attempts have been made (1, 2) to use CO chemisorption to count surface Cu atoms, but the results are uncertain because of extensive physical adsorption, especially when a support of high surface area is used, and because of the unknown CO/Cu<sub>s</sub> stoichiometry. Several groups of workers have employed  $O_2$  chemisorption, but the success of this method depends upon the conditions used and upon the state of the catalyst. Chemisorption of O<sub>2</sub> is accompanied by slow partial oxidation of the bulk metal at temperatures above ambient (3), and if the Cu crystallites are sufficiently small (i.e., <10 nm) they may be quickly and totally oxidized even at 77 K (4). Nevertheless this method can afford reliable results if the operating conditions are carefully controlled (5).

Attention in recent years has been concentrated however on the use of N<sub>2</sub>O to form a layer of chemisorbed O atoms on the Cu metal surface (4, 6–12): the O/Cu<sub>s</sub> ratio is believed to be 0.5. There is however no agreement as to the optimum temperature at which the reaction should be performed. Scholten and Konvalinka (4) and Evans *et al.* (7) favor 363–373 K because irreproducible results are obtained at lower temperatures and bulk oxidation is significant above 393 K. Other workers however believe that bulk oxidation starts as low as 340 K (8), although many have concluded that no substantial change in the uptake of  $N_2O$  occurs between 293 and 353 K (9–11).

A variety of techniques has also been used to determine the extent of the reaction of N<sub>2</sub>O with Cu catalysts. Dell *et al.* (6) and Osinga *et al.* (9) employed a static system; they froze out unreacted N<sub>2</sub>O and measured the residual N<sub>2</sub> volumetrically. Scholten and Konvalinka (4) used thermal conductivity to analyze the gas above the catalyst after dosing with N<sub>2</sub>O, while Giamello *et al.* (11) have used microcalorimetry to follow the interaction. Various forms of the pulsed chromatographic method have also been tried (12, 13).

The method to be described minimizes the disadvantages (5) associated with the volumetric and pulse-flow methods, namely, the inherent inaccuracy associated with measuring very low N<sub>2</sub> pressures in the former case and the difficulty of identifying conditions giving complete reaction but no bulk oxidation in the latter. It involves reacting reduced Cu catalysts with pure N<sub>2</sub>O under conditions expected to lead to the formation of a complete layer of O atoms having an O/Cu<sub>s</sub> ratio of 0.5, but without oxidation of the bulk metal, and then determining the number of chemisorbed O atoms by temperature-programmed reduction (TPR). Whereas the methods used previously have derived this number by inference, the presence technique measures it directly and is therefore expected to be more accurate and reliable.

#### EXPERIMENTAL

Cu catalysts were prepared on three supports (Aerosil 200, Degussa  $Al_2O_3$ -C, and

### NOTES

Catalyst	Method <sup>a</sup>	Cu content (wt%)		Cu area $(m^2 a^{-1})$	Dispersion	Rate $(mmol h^{-1} m^{-2})$
		By AA	By TPR	(III- g <sub>Cu</sub> )	(70)	(11110) 11 - 111 -)
Cu/SiO <sub>2</sub>	IE	6.3	3.8	335	52.0	0.076
10% Cu/SiO <sub>2</sub>	DP	5.6	5.4	93	14.4	0.148
5% Cu/SiO <sub>2</sub>	DP	4.2	3.6	253	39.2	0.060
10% Cu/SiO <sub>2</sub>	Impr.	7.2	7.6	56	5.3	0.025
5% Cu/SiO <sub>2</sub>	Impr.	4.3	4.4	33	5.3	0.061
10% Cu/TiO <sub>2</sub>	Impr.	8.6	7.9	28	4.3	0.028
5% Cu/TiO <sub>2</sub>	Impr.	5.0	3.1	66	10.3	0.029
10% Cu/Al <sub>2</sub> O <sub>3</sub>	Impr.	7.5	5.1	239	37.0	0.100
5% Cu/Al <sub>2</sub> O <sub>3</sub>	Impr.	4.1	4.3	199	30.4	0.051

TABLE 1

Characteristics of Supported Cu Catalysts and Their Rates for CO<sub>2</sub> Hydrogenation at 673 K

<sup>a</sup> IE, ion exchange; DP, deposition-precipitation; Impr., impregnation.

Degussa P-25 TiO<sub>2</sub>) by (i) impregnation to incipient wetness with a solution of  $Cu(NO_3)_2$  (14), (ii) ion exchange with  $[Cu(NH_3)_4]^{2+}$  (15), and (iii) deposition-precipitation of  $Cu(OH)_2$  (16). Various Cu concentrations were used as shown in Table 1. Precursors were dried overnight in an air oven at 400 K and were then calcined for 5 h at 773 K in a stream of air. Cu contents were determined by atomic absorption (AA) spectroscopy (see Table 1), and also by TPR as described below.

TPR apparatus of standard design (17) was modified to allow flows of (i) 5%  $H_2$  in Ar, (ii) pure Ar, and (iii) pure  $N_2O$  to be passed sequentially through the reactor and detector. A normal TPR was first performed on a calcined sample: this permitted an estimate of the Cu content, assuming that calcination in each case afforded CuO, and also produced a reduced Cu catalyst thoroughly free from all adsorbed species and in a suitable state for reaction with  $N_2O$ . The heating rate was 5 K min<sup>-1</sup> and the flow rate of the gas was 40 cm<sup>3</sup> min<sup>-1</sup>. Reduction peaks were symmetrical, having values of  $T_{\text{max}}$  of about 473 K, with an accompanying smaller peak at 503-573 K. Reduction was stopped at 623 K in order to avoid sintering of the Cu crystallites. This temperature appeared to be high enough to secure complete reduction to Cu metal, but it is a further advantage of this method that the  $H_2$  consumption in this first TPR may be used to give a direct estimate of the amount of reduced Cu present in the sample (see Table 1). The detector response was calibrated by injecting doses of pure  $H_2$ .

The sample was then cooled to the reaction temperature, normally 333 K, in O<sub>2</sub>free Ar (obtained by passing Ar through a bed of SiO<sub>2</sub>-supported MnO) and after 30 min pure N<sub>2</sub>O was allowed to flow over the sample for 1 h at this temperature (flow rate 81 cm<sup>3</sup> min<sup>-1</sup>). The N<sub>2</sub>O flow was then replaced by Ar and the sample cooled to room temperature. The  $H_2/Ar$  mixture was then introduced and a second TPR carried out. A peak due to the reduction of the adsorbed O atoms was observed: it was symmetrical, and values of  $T_{\text{max}}$  were in the range 403-423 K, i.e., significantly lower than for the principal peak in the reduction of CuO. After the second TPR, a further calibration with a dose of pure H<sub>2</sub> was carried out, and the number of surface Cu atoms,  $Cu_s$ , computed assuming O/Cu<sub>s</sub> = 0.5. The dispersion, Cu<sub>s</sub>/Cu<sub>tot</sub>, was then calculated using the Cu content as determined by TPR, and also the Cu surface area (assuming  $1.47 \times 10^{19}$  atoms m<sup>-2</sup>, this being the mean for the three low Miller Index planes).

## **RESULTS AND DISCUSSION**

A selection of the results is shown in Table 1. Except in two cases, the agreement between the Cu contents as estimated by AA spectroscopy and by TPR is satisfactory. The observed dispersion is markedly dependent on both the support and the method of preparation. With SiO<sub>2</sub>, ion exchange and deposition-precipitation both afford high dispersions, markedly better than those obtained with the impregnation method. This last method, however, gives quite good dispersions with Al<sub>2</sub>O<sub>3</sub> but not with TiO<sub>2</sub>. Kuijpers *et al.* (18) reported that a 10% Cu/SiO<sub>3</sub> catalyst made by deposition-precipitation had a metal area of 90  $m^2 g_{Cu}^{-1}$ , in very good agreement with what we find (Table 1).

The Cu content of the Cu/SiO<sub>2</sub> catalyst made by ion exchange seems high ( $\sim 6\%$ ). On the basis of an assumed Si-OH concentration of  $3 \times 10^{18} \text{ m}^{-2}$  (19), the maximum Cu content is calculated to be 3.2%. As has been recently pointed out (19), such a high value is probably caused by the precipitation of  $Cu(OH)_2$  from the solution of  $[Cu(NH_3)_4]^{2+}$  in the pores as the pH is lowered by washing. This method therefore in fact closely resembles the deposition-precipitation method. The so-called ion exchange method has been reported (19) to give well-dispersed Cu particles (Cu area 249 m<sup>2</sup>  $g_{Cu}^{-1}$  for 4.1% Cu/SiO<sub>2</sub>, measured as described by Wainwright et al. (7)), in agreement with the first and third entries in Table 1.

As noted above, the reaction of the  $N_2O$  with the Cu surface was normally conducted at 333 K. In order to determine the sensitivity of the resulting estimate of the number of O atoms chemisorbed to the reaction temperature, measurements were also made with the 10% Cu/Al<sub>2</sub>O<sub>3</sub> catalyst using temperatures of 343 and 363 K. Values for the Cu areas obtained were, respectively, 241 and 242 m<sup>2</sup>  $g_{Cu}^{-1}$ , in excellent agreement with the value of 239 m<sup>2</sup>  $g_{Cu}^{-1}$ given in Table 1, where the temperature used was 333 K. These results suggest very strongly that the reaction temperature used is not critical and that no bulk oxidation occurs (at least with this catalyst) up to 363 K.

The hydrogen of CO<sub>2</sub> (the reverse watergas shift reaction) was performed in a glass recirculation system (20): catalysts were initially reduced at 523 K for 1 h 80 Torr H<sub>2</sub>, the H<sub>2</sub>O being removed continuously by condensation. In seeking to relate the observed rates at 673 K (Table 1) to the measured Cu areas, one must assume that the areas produced by this reduction schedule and in the TPR procedure are the same. The TP reduction achieved a higher temperature (623 K) but used a lower H<sub>2</sub> pressure (40 Torr), the effects of which may compensate.

The reliability of the TPR method for estimating Cu areas is shown by the generally satisfactory correlation between Cu areas and rates of CO<sub>2</sub> hydrogenation (Table 1). Catalysts having low activity have Cu areas in the range 28–66 m<sup>2</sup> g<sub>Cu</sub><sup>-1</sup>, whereas those of high activity (10–25 mmol h<sup>-1</sup> g<sub>Cu</sub><sup>-1</sup>) have areas in excess of 200 m<sup>2</sup> g<sub>Cu</sub><sup>-1</sup>. The only exception to this generalization is the 10% Cu/SiO<sub>2</sub> made by deposition–precipitation, which shows high activity, notwithstanding a somewhat low Cu area. These results will be described more fully in a future publication.

We conclude that the use of TPR to estimate O atoms formed on Cu surfaces by dissociation of N<sub>2</sub>O constitutes a direct, tolerant, and simple method for determining Cu surface area, dispersion, and particle size in supported Cu catalysts. TPR permits a distinction to be drawn between chemisorbed O atoms and Cu formed by overoxidation, and a separate assessment of each where necessary. A given sample may also be speedily reexamined in order to refine the accuracy of the measurement.

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#### REFERENCES

- Emmett, P. H., and Skau, N., J. Amer. Chem. Soc. 65, 1029 (1943).
- Sinfelt, J. H., Taylor, W. F., and Yates, D. J. C., J. Phys. Chem. 69, 95 (1965).
- Allen, J. A., and Mitchell, J. W., Discuss. Faraday Soc. 8, 1815 (1950).
- 4. Scholten, J. J. F., and Konvalinka, J. A., *Trans. Faraday Soc.* **65**, 2465 (1965).
- 5. Parris, G. E., and Klier, K., J. Catal. 97, 374 (1986).
- 6. Dell, R. M., Stone, F. S., and Tiley, P. F., *Trans. Faraday Soc.* **49**, 195 (1953).
- Evans, J. W., Wainwright, M. S., Bridgwater, A. J., and Young, D. J., *Appl. Catal.* 7, 75 (1983).
- 8. Sengupta, G., Gupta, D. K., Kundu, M. L., and Sen, S. P., J. Catal. 67, 223 (1983).
- Osinga, T. J., Linsen, B. G., and van Beet, W. P., J. Catal. 7, 277 (1967).
- Narita, K., Takeyawa, N., Kobayashi, H., and Toyoshima, I., *React, Kinet. Catal. Lett.* 19, 91 (1982).
- Giamello, E., Fubini, B., Lauro, P., and Bossi, A., J. Catal. 18, 108 (1970).
- 12. Dvorak, B., and Pasek, J., J. Catal. 18, 108 (1970).

- 13. Chinchen, G. C., Hay, C. M., Vandervell, H. D., and Waugh, K. C., J. Catal. 103, 79 (1987).
- Bond, G. C., "Heterogeneous Catalysis: Principles and Applications," 2nd ed. Oxford Chemistry Series, 1987.
- Satterfield, C. N., "Heterogeneous Catalysis in Practice." McGraw-Hill, New York, 1980.
- Geus, J. W., *in* "Heterogeneous Catalysis in Practice." McGraw-Hill, New York, 1980.
- 17. Gentry, S. J., Hurst, N. W., and Jones A., J. Chem. Soc. Faraday Trans. 1 77, 603 (1981).
- Kuijpers, E. G. M., Tjepkema, R. B., van der Wal, W. J. J., Mesters, C. M. A. M., Spronck, S. F. G. M., and Geus, J. W., *Appl. Catal.* 25, 139 (1986).
- 19. Lee, J. C., Trimm, D. L., Kohler, M. A., Wainwright, M. S., and Cant, N. W., *Catal. To*day 2, 643 (1988).
- S. N. Namijo, Ph.D. thesis, Brunel University, 1988.

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